

Vishay General Semiconductor

Ultrafast Plastic Rectifier



1.0 A

200 V

35 A

25 ns

0.710 V

175 °C

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

I_{FSM}

t_{rr}

 V_{F}

T_{.1} max.

FEATURES

- Glass passivated chip junction
- Ultrafast reverse recovery time
- Low forward voltage drop
- Low leakage current
- · Low switching losses, high efficiency
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

MECHANICAL DATA

Case: DO-204AC (DO-15)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

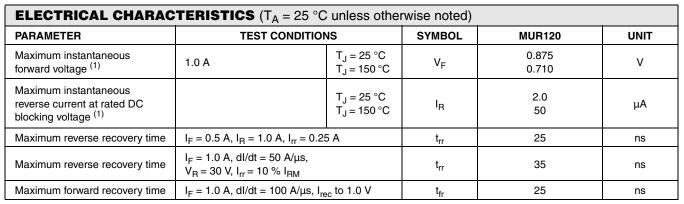
Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MUR120	UNIT			
Maximum repetitive peak reverse voltage	V _{RRM}	200	V			
Working peak reverse voltage	V _{RWM}	200	V			
Maximum DC blocking voltage	V _{DC}	200	V			
Maximum average forward rectified current at T_A = 130 °C	I _{F(AV)}	1.0	А			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	35	A			
Operating and storage temperature range	T _J , T _{STG}	- 65 to + 175	°C			





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Note:

(1) Pulse test: t_p = 300 μs pulse, duty cycle \leq 2 %

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MUR120	UNIT		
Typical thermal resistance junction to ambient ⁽¹⁾	$R_{ hetaJA}$	27	°C/W		

Note:

(1) Lead length = 3/8" on P.C. Board with 1.5" x 1.5" copper surface

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
MUR120-E3/54	0.41	54	4000	13" diameter paper tape and reel		
MUR120-E3/73	0.41	73	2000	Ammo pack packaging		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

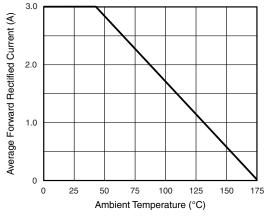


Figure 1. Forward Current Derating Curve

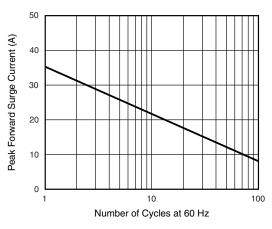


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



MUR120

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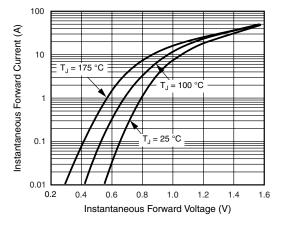


Figure 3. Typical Instantaneous Forward Characteristics

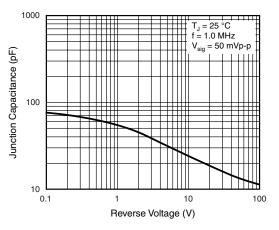


Figure 5. Typical Junction Capacitance

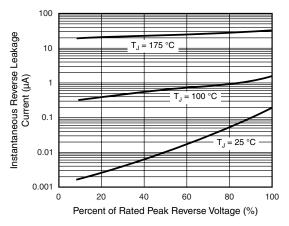
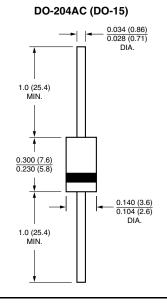


Figure 4. Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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